TOSHIBA



TOSHIBA CORPORATION

Semiconductor Company

Document Change Notification

The purpose of this notification is to inform customers about the launch of the Pb free version of the device. The introduction of a Pb-free replacement affects the datasheet. Please understand that this notification is intended as a temporary substitute for a revision of the datasheet.

Changes to the datasheet may include the following, though not all of them may apply to this particular device.

- 1. Part number
 - Example: TMPxxxxxF TMPxxxxxFG

All references to the previous part number were left unchanged in body text. The new part number is indicated on the prelims pages (cover page and this notification).

2. Package code and package dimensions

Example: LQFP100-P-1414-0.50C LQFP100-P-1414-0.50F

All references to the previous package code and package dimensions were left unchanged in body text. The new ones are indicated on the prelims pages.

3. Addition of notes on lead solderability

Now that the device is Pb-free, notes on lead solderability have been added.

4. RESTRICTIONS ON PRODUCT USE

The previous (obsolete) provision might be left unchanged on page 1 of body text. A new replacement is included on the next page.

5. Publication date of the datasheet

The publication date at the lower right corner of the prelims pages applies to the new device.

1. Part number

2. Package code and dimensions

Previous Part Number (in Body Text)	Previous Package Code (in Body Text)	New Part Number	New Package Code	OTP
TMP47P403VN	P-SDIP28-400-1.78	TMP47P403VNG	SDIP28-P-400-1.78	—
TMP47P403VM	P-SOP28-450-1.27	TMP47P403VMG	SOP28-P-450-1.27B)	—

*: For the dimensions of the new package, see the attached Package Dimensions diagram.

3. Addition of notes on lead solderability

The following solderability test is conducted on the new device,

Lead solderability of Pb-free devices (with the G suffix)

Test	Test Conditions	Remark
Solderability	 (1) Use of Lead (Pb) solder bath temperature = 230°C dipping time = 5 seconds the number of times = once use of R-type flux (2) Use of Lead (Pb)-Free solder bath temperature = 245°C dipping time = 5 seconds the number of times = once use of R-type flux 	Leads with over 95% solder coverage till lead forming are acceptable.

4. RESTRICTIONS ON PRODUCT USE

The following replaces the "RESTRICTIONS ON PRODUCT USE" on page 1 of body text.

RESTRICTIONS ON PRODUCT USE

• The information contained herein is subject to change without notice.

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• TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.

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- For a discussion of how the reliability of microcontrollers can be predicted, please refer to Section 1.3 of the chapter entitled Quality and Reliability Assurance/Handling Precautions.

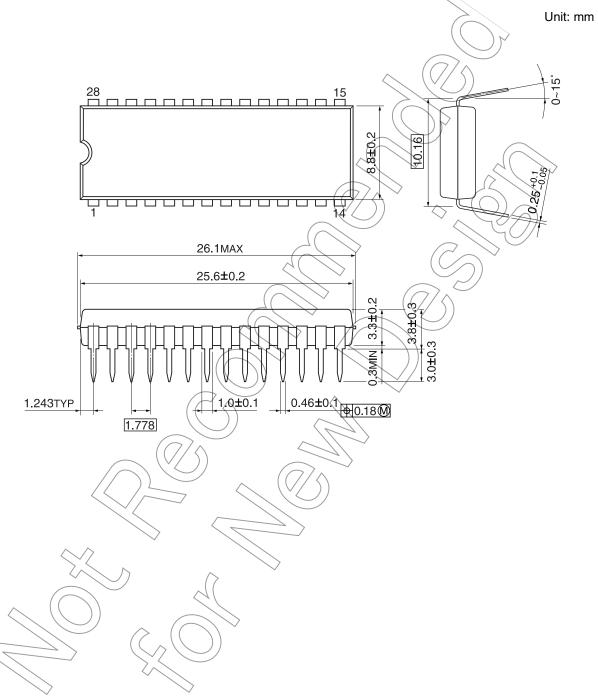
5. Publication date of the datasheet

The publication date of this datasheet is printed at the lower right corner of this notification.

(Annex)

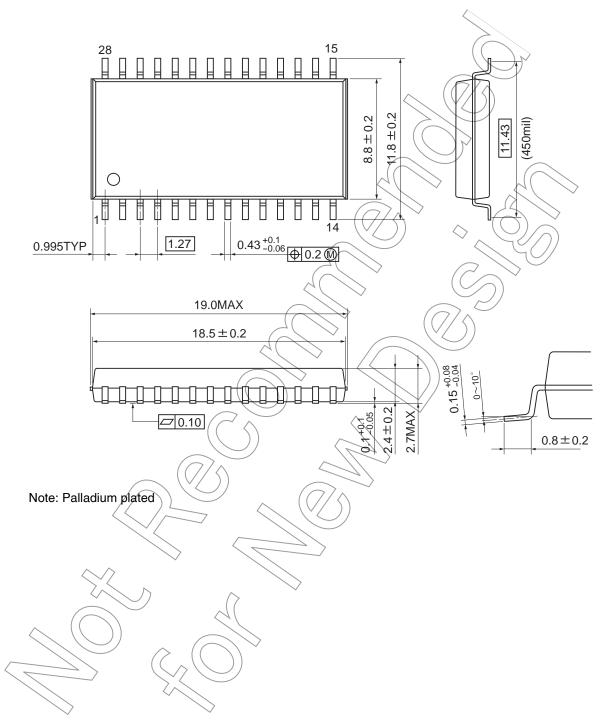
Package Dimensions

SDIP28-P-400-1.78



SOP28-P-450-1.27B

Unit: mm



CMOS 4-Bit Microcontroller

TMP47P403VN TMP47P403VM

The TMP47P403V is the system evaluation LSI of TMP47C103/203 with a 32-Kbit one-time PROM. The TMP47P403V programs / verifies using an adapter socket to connect with PROM programmer, as it is in TMM27256AD.

In addition, the TMP47P403V and the TMP47C103/203 are pin compatible. The TMP47P403V operates as the same as the TMP47C103/203 by programming to the internal PROM.

	Part No.	ROM	RAM	Package	Adaptor Socket	
	TMP47P403VN	OTP 4096 x 8-bit	128 x 4-bit	P-SDIP28-400-1.78	BM1140	
	TMP47P403VM	4096 X 8-DIL		P-SOP28-450-1.27	BM1141	
Pin Assian	ment (Top View)				
i in Assign		,		P-SDIP28-4		
P-SDID28-400	0-1.78 / P-SOP28-450	1 27	(
F-3DIF20-400	J-1.787 F-30F28-430	-1.27	10			
				\sim	(
			$\langle \langle \rangle$	\diamond		
	OUT ← 🗌 1		- VDD			
	$XIN \longrightarrow \square 2$	27 🗆 🗲	— <u>НФЦД (КЕФ)</u> / VF	и (()		
RE	SET → 🛛 3	26 🗖 🔫	R92 (SCK) / CE			
15 / R70 (W	/TO) \leftrightarrow 🗖 4	25 🗖 🔫	🗧 R91 (SO)/ OE		TMP47P403VN	
16 /	R71 ↔ 🗖 5	24 🗆 🗲	► R90 (SI) / 14			
17/	R72 \leftrightarrow 🗖 6	23 🗋 🐳	🗕 R83 (TC1) / I3			
A0/	R40 \leftrightarrow 🗌 7		► R82 (INT1) / 12	P-SOP28-45	50-1.27	
A1/	R41 ↔ 🗆 8		R81 (TC2) / 11			
A2/	R42 \leftrightarrow 🗆 9		R80 (INT2) / 10	$\langle \rangle$		
	R43 ↔ [] 10		► R63/A11		~	
	R50 ↔ □ 11	\frown	► R62/A10			
	R51 ↔ □ 12	$\left(\left(\right) \right) \left(\left(\right) \right) \left(\left(\right) \right) \left(\left(\right) \right) \left(\left(\left(\right) \right) \right) \left(\left(\left(\left(\right) \right) \right) \left($	► R61/A9	\geq	MARKE	
	$R52 \leftrightarrow \square 13$		- R60/A8	\sim	THE REAL OF	
)	TMP47P403VM	
	VSS - L 14		► R53/A7	/		
				1		
	\sim	$>$ $\langle <$				

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- For a discussion of how the reliability of microcontrollers can be predicted, please refer to Section 1.3 of the chapter entitled Quality and Reliability Assurance / Handling Precautions.
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 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products products or "TOSHIBA Semiconductor Reliability Handbook" etc..
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- transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.

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Pin Function

The TMP47P403V has MCU mode and PROM mode.

- (1) MCU mode The TMP47C103/203 and the TMP47P403V are pin compatible.
- (2) PROM mode

Pin Name	Input / Output	Functions	Pin Name (MCU mode)
A11 to A8			R63 to R60
A7 to A4	Input	Address inputs	R53 to R50
A3 to A0			R43 to R40
17 to 15		$(7/5)^{\sim} \sim ($	R72 to R70
14	I/O	Data inputs / outputs	R90
13 to 10			R83 to R80
CE	Input	Chip Enable input	R92
ŌĒ		Output Enable input	R91
VPP		+ 12.5 V / 5 V (Program supply voltage)	HOLD
vcc	Power supply	+ 5 V	VDD
VSS		0 V (())	VSS
RESET	Input	PROM mode setting pin. Be fixed to low level.	
XIN	Input	Input the clock from the external oscillator.	
XOUT	Input	Be pulled up to VCC level (Z50 & typ.)	

Operational Description

The following is an explanation of hardware configuration and operation in relation to the TMP47P403V. The TMP47P403V is the same as the TMP47C103/203 except that an OTP is used instead of a built-in mask ROM.

1. Operation mode

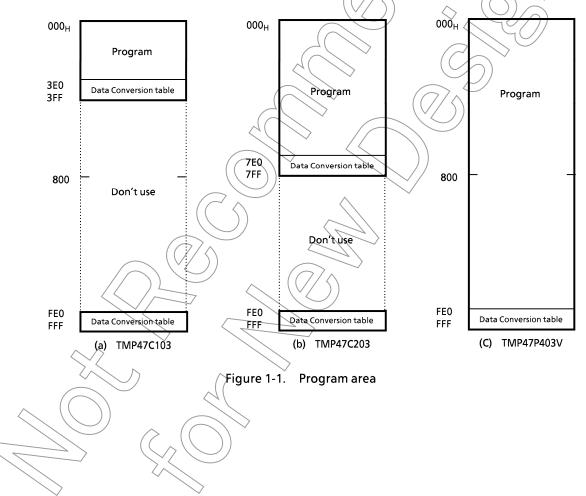
The TMP47P403V has an MCU mode and a PROM mode.

1.1 MCU mode

The MCU mode is set by attaching a resonator between the XIN and Xout pins. Operation in the MCU mode is the same as for the TMP47C103/203. In the TMP47P403V, RC oscillation is impossible.

1.1.1 Program Memory

The program storage area are as shown in Figure 1-1. Data conversion tables must be set in two locations when using the TMP47P403V to check TMP47C103/203 operation.

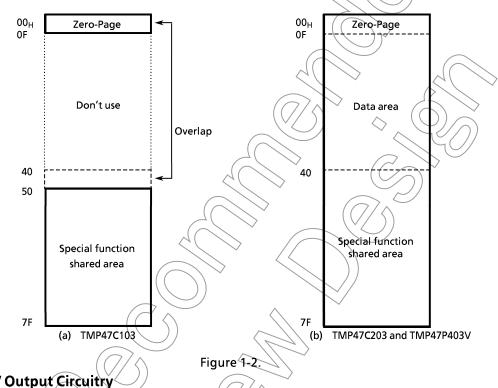


1.1.2 Data Memory

The TMP47P403V has 128×4 -bit of data memory (RAM). When the TMP47P403V is used as the TMP47C103 evaluator, programming should be performed assuming that the RAM is assigned to addresses $00_{\rm H}$ to $0F_{\rm H}$ and $50_{\rm H}$ to $7F_{\rm H}$ as shown in Figure 1-2 (a).

At the Real time emulator (BM47C203), RAM is assigned to addresses 00_H to FF_H. However, programming should be performed assuming that the RAM is assigned as shown in Figure 1-2 (a).

Further, zero-page (addresses 00_H to $0F_H$) and special function shared area (Stack location 0 to 3) are overlapped on the TMP47C103.



1.1.3 Input / Output Circuitry

(1) Control pins

This is the same as for the TMP47C103/203. In the TMP47P403V, RC oscillation is impossible. Connecting the resonator or inputting the external check to XIN pin are required when using as evaluator of I/O code FD, FE.

(2) I/O Ports

The input/output circuit of the TMP47P403V is the same as I/O code FA, FD of the TMP47C103/203. External resistance, for example, is required when using as evaluator of other I/O codes (FB, FE).



Figure 1-3. I/O code and external circuitry

1.2 PROM mode

The PROM mode is set by inputting the external clock to the XIN pin when XOUT pin is pulled up to the VCC level. In PROM mode, programs can be written or verified using a general-purpose PROM writer with an adapter socket being attached.

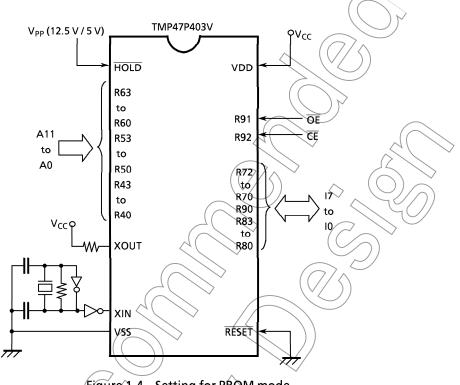
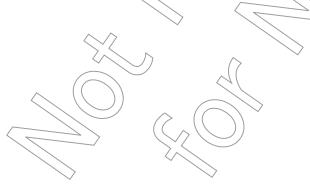


Figure 1-4. Setting for PROM mode

1.2.1 Program Writing

When writing a program, set a ROM type to "27256A" (programming voltage: 12.5 V). Since the TMP47P403V has a 4096 x 8-bit internal PROM (000 to FFF_H), set a stop address of a PROM writer to "FFF_H". For a general-purpose PROM writer, use the writer which does not have or can release an electric signature mode.



1.2.2 **High Speed Programming Mode**

The program time can be greatly decreased by using this high speed programming mode. The device is set up in the high speed programming mode when the programming voltage (+ 12.5 V) is applied to the V_{PP} terminal with $V_{CC} = 6 V$ and $\overline{CE} = V_{IH}$.

The programming is achieved by applying a single low level 1ms pulse the $\overline{\text{CE}}$ input after addresses and data are stable. Then the programmed data is verified by using Program Verify Mode.

If the programmed data is not correct, another program pulse of 1ms is applied and then programmed data is verified. This should be repeated until the program operates correctly (max. 25 times).

After correctly programming the selected address, one additional program pulse with pulse width 3 times that needed for programming is applied.

When programming has been completed, the data in all addresses should be verified with $V_{CC} = V_{PP} = 5 V$.

START ADDRESS = START ADDRESS (¥ Vcc=6¥ V_{pp} = 12.5 V DATA = FF? X = 0 PROGRAM 1 ms PULSE X = X + 1

¥.

X=25?

VERIFY

OVERPROGRAM 3X PULSES of 1)ms or ONE PULSE of 3X ms DURATION

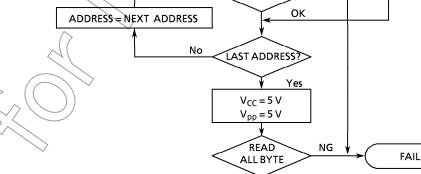
VERIFY

No

ΟК

Yes

NG



NG

Figure 1-5. Flowchart

∳ ок PASS

Electrical Characteristics

Absolute Maximum Ratings	(V _{SS} =)	א כ(א כ		
Parameter	Symbol	Pins	Ratings	Unit
Supply Voltage	V _{DD}		= 0.3 to 6.5	V
Program Voltage	V _{PP}	HOLD / VPP pin	🔿 – 0.3 to 13.0	V
Input Voltage	V _{IN}		-0.3 to V _{DD} + 0.3	V
Output Voltage	V _{OUT}		- 0.3 to V _{DD} + 0.3	V
	I _{OUT1}	Port R5, R6	30	
Output Current (Per 1 pin)	I _{OUT2}	Port R4	15	mA
	I _{OUT3}	Ports R7, R8, R9	3.2	
Output Current (Total)	ΣI_{OUT}	Port R4, R5, R6	(120	mA
Power Dissipation [Topr = 70°C]	PD		300	mW
Soldering Temperature (time)	Tsld		260(10/5)	°C
Storage Temperature	Tstg		- 55 to 125	°C
Operating Temperature	Topr		-30 to 70	°C

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

(Vss =)0 V, Topr = - 30 to 70°C)

Parameter	Symbol	Pins	Conditions	Min	Max	Unit
			₹c=6:0 MHz	4.5		
Supply Voltage	VDD	7/~	fc = 4.2 MHz	2.7	5.5	V
($\sum ('$	$(\langle \rangle) $	HOLD mode	2.0		
//	Ун 1	Except Hysteresis Input (n the normal	V _{DD} × 0.7		
Input High Voltage	/V _{1H2}	Hysteresis Input	operating area	V _{DD} × 0.75	V _{DD}	V
\sim	Č ⟨VIH3		In the HOLD mode	V _{DD} × 0.9		
	V _{IL1}	Except Hysteresis Input	In the normal		V _{DD} × 0.3	
Input Low Voltage	V _{IL2}	Hysteresis Input	operating area	0	V _{DD} × 0.25	V
	V _{IL3}	\sim	In the HOLD mode		V _{DD} × 0.1	
) fa		V _{DD} = 4.5 to 5.5 V	0.4	6.0	MHz
Clock Frequency	fc	XIN, XOUT	V _{DD} = 2.7 to 5.5 V	0.4	4.2	IVIHZ

 Note:
 The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions

for the device are always adhered to.

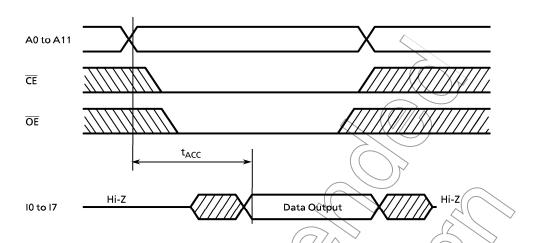
Recommended Operating Conditions

DC Character	ristics	(V _{SS} = 0 V, Topr	= – 30 to 70°C)				
Parameter	Symbol	Pins	Conditions	Min	Тур.	Max	Unit
Hysteresis Voltage	V _{HS}	Hysteresis Input			0.7	-	v
	I _{IN1}	RESET, HOLD		\sim			
Input Current	I _{IN2}	Open drain output ports	$V_{DD} = 5.5 V, V_{IN} = 5.5 V / 0 V$	Ì	-	± 2	μΑ
Input Resistance	R _{IN}	RESET		100	220	450	kΩ
Input Low Current	Ι _{ΙL}	Push-pull output ports	$V_{DD} = 5.5 V, V_{IN} = 0.4 V$	-	1	-2	mA
Output Leakage Current	ILO	Open drain output ports	V _{DD} = 5.5 V, V _{OUT} = 5.5 V	-	4	2	μA
Output Low Voltage	V _{OL}	Port R7, R8, R9	$V_{DD} = 4.5 V, V_{OL} = 1.6 mA$	-6		0.4	v
	I _{OL1}	Port R5, R6	\bigcirc	<u>_</u>	20	\rightarrow -	
Output Low Current	I _{OL2}	Port R4	$V_{DD} = 4.5 V, V_{OL} = 1.0 V$	7 -		-	mA
Supply Current			$V_{DD} = 5.5 V$, fc= 4 MHz	()	2	4	
Supply Current (in the Normal	I _{DD}	($V_{DD} = 3.0 V_{\gamma} \text{ fc} = 4 \text{ MHz}$	<u>~</u>	1	2	mA
operating mode)			V _{DD} =3.0 V, fc=400 kHz) _	0.5	1	
Supply Current (in the HOLD operating mode)	I _{DDH}		V _{DD} = 5.5 V	_	0.5	10	μΑ

Note 1: Typ. values show those at Topr = 25° C, $V_{DD} = 5 \text{ V}$.

- Note 2: Input Current I_{IN1}: The current through resistor is not included.
- Note 3: Supply Current: $V_{IN} = 5.3 V(0.2 V (V_{DD} = 5.5 V), 2.8 V (0.2 V (V_{DD} = 3.0 V))$

Parameter	Symbol	Conditions	Min		Тур.	Vlax	Unit
		V _{DD} = 4.5 to 5.5 V			\square	20	
nstruction Cycle Time	t _{cy}	V _{DD} = 2.7 to 5.5 V	1.9	1.9		20 µs	μS
ligh level Clock pulse Width	t _{WCH}		20	$\langle \bigcirc$			
ow level Clock pulse Width	t _{WCL}	For external clock operation	80	$\langle \rangle \rangle$	-	-	ns
hift data Hold Time	t _{SDH}		0.5 t _{cy} - 0).3	- /		μs
VDD		SCK				1.5 V	>
Recommended Oscillat Recommended os oscillation is impossi DC/AC Characteristics (1) Read Operation	cillating	conditions of the TMP47P40					3's but
Recommended os oscillation is impossi DC/AC Characteristics	cillating ble.	conditions of the TMP47P40			MP47C1		3's but
Recommended os oscillation is impossi DC/AC Characteristics (1) Read Operation	cillating ble.	conditions of the TMP47P40	3V are equal	to the Ti	MP47C1	103/203	
Recommended os oscillation is impossi DC/AC Characteristics (1) Read Operation Parameter	cillating ble.	conditions of the TMP47P40	3V are equal	to the Ti Typ.	MP47C1	103/203 Max	Unit
Recommended os oscillation is impossi DC/AC Characteristics (1) Read Operation Parameter Output Level High Voltage	cillating ble.	conditions of the TMP47P40	3V are equal Min V _{CC} ×0.7	to the TI Typ. –	MP47C1	103/203 Max V _{CC}	Unit V



(2) High Speed Programming Operation

Symbol	Condition	Min	Тур.	Max	Unit
V _{IH4}		V _{CC} × 0.7		V _{cc}	V
V _{IL4}		0 (($\overline{2}$	V _{CC} × 0.3	V
V _{CC}		4.75	$\underline{\bigcirc}$	6.0	V
V _{PP}		12.00	12.50	13.00	V
t _{PW}	$V_{CC} = 6.0 \pm 0.25 V$	0.95	1.0	1.05	ms
	V _{IH4} V _{IL4} V _{CC} V _{PP}	V _{IH4} V _{IL4} V _{CC} V _{PP}	V _{IH4} V _{CC} × 0.7 V _{IL4} 0 V _{CC} 4.75 V _{PP} 12.00	V _{IH4} V _{CC} × 0.7 V _{IL4} 0 V _{CC} 4.75 V _{PP} 12.00 12.50	V _{IH4} V _{CC} ×0.7 V _{CC} V _{IL4} 0 - V _{CC} ×0.3 V _{CC} 4.75 - 6.0 V _{PP} 12.00 12.50 13.00

